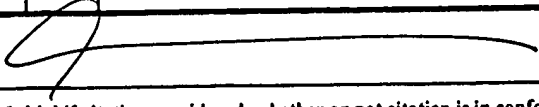


10/695,335

INFORMATION DISCLOSURE CITATION <i>(Use several sheets if necessary)</i>				Docket Number (Optional) BUR920010040US1(145 .)		Application Number Unassigned		
				Applicant(s) Jeffrey P. Gambino, et al.				
				Filing Date Herewith		Group Art Unit 2814 Unassigned		
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*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
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							YES	NO
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gn		Chang, L., "Industrial Planar FinFET Fabrication Using Standard Processing Tools," (last modified February 21, 2001), p. 1, < http://hera.berkeley.edu/IRO/Summary/01abstracts/leland.2.html >						
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EXAMINER 				DATE CONSIDERED 9/22/2004				
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.								